

Title (en)
Plasma reactor

Title (de)
Plasmareaktor

Title (fr)
Réacteur à plasma

Publication
EP 1837067 A3 20090415 (EN)

Application
EP 07250597 A 20070214

Priority
JP 2006078625 A 20060322

Abstract (en)

[origin: EP1837067A2] A plasma reactor (100) including a plasma generating electrode (1) which includes a plurality of unit electrodes (2) hierarchically layered at specific intervals, a casing (11) in which the plasma generating electrode (1) is disposed, and a power supply (21) which applies a voltage to the unit electrodes (2), generating plasma in a space (3) formed between the unit electrodes (2) by applying a pulse voltage between the unit electrodes (2) from the power supply (21), and capable of processing exhaust gas introduced into the space (3) through reaction, the plasma reactor (100) further including a light-transmitting section (12) formed in the casing (11) for externally detecting light emitted by the plasma, light detection means (31) capable of detecting light emitted by the plasma through the light-transmitting section (12), and control means (41) for controlling electric energy applied to the unit electrodes (2) depending on intensity of light detected by the light detection means (31).

IPC 8 full level

B01D 53/32 (2006.01); **F01N 3/08** (2006.01)

CPC (source: EP US)

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B01D 2259/818 (2013.01 - EP US); **F01N 3/027** (2013.01 - EP US); **F01N 2240/28** (2013.01 - EP US); **F01N 2330/06** (2013.01 - EP US);
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Y02T 10/40 (2013.01 - EP US); **Y10S 422/906** (2013.01 - EP)

Citation (search report)

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Designated contracting state (EPC)

AT BE BG CH CY CZ DE DK EE ES FI FR GB GR HU IE IS IT LI LT LU LV MC NL PL PT RO SE SI SK TR

Designated extension state (EPC)

AL BA HR MK RS

DOCDB simple family (publication)

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JP 2007255255 A 20071004; JP 4619969 B2 20110126; US 2007223641 A1 20070927; US 7508140 B2 20090324

DOCDB simple family (application)

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